

Lab 5 – Load/Store Operation and Data Memory Interface

The load/store operations are performed for data transfer from/to data memory. To implement these operations we first need to connect data memory with the processor data path at the data memory access phase. A simple tightly coupled data memory interface is shown in figure below.

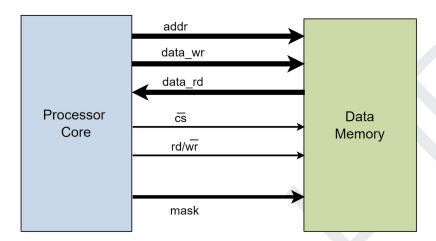


Figure 5.1. Data memory interface.

The data write operation is performed by setting up the address (addr), data to be written (data_wr) and mask followed by the cs and wr signals. The memory write operation is synchronous. The mask signal is used to inform the memory 1) the size of the data to be written, which can be of size byte, half-word or word and, 2) the location of the byte/half-word on a bus width equal to word size.

Load Operation – Memory Access Phase (M)

The code segment below illustrates setting up the signals during the data memory access phase when performing a load or store operation.

Listing 5.1. Setting up the signals in the data memory access phase for load/store operation.

The data load operation corresponds to memory read and here for single cycle implementation we have used asynchronous memory read. The mask signal is of no significance because the load operation always receives 32-bit data from data memory as can be observed from the following code segment.

```
// Asynchronous read operation
```

Listing 5.2. Asynchronous data memory read for load operation.

The received 32-bit data is processed during the data memory access phase for the requested size and the corresponding address location.

```
// Extract the right size from the read data
always comb begin
   dmem rdata byte = '0;
   dmem_rdata_hword = '0;
   dmem_rdata_word = '0;
   case (exe2mem ctrl.mem ld ops)
      MEM LD OPS LB,
      MEM_LD_OPS_LBU : begin
         case (mem2dmem.addr[1:0])
            2'b00 : begin
               dmem rdata byte = dmem2mem.data rd[7:0];
            end
            2'b01 : begin
               dmem rdata byte = dmem2mem.data rd[15:8];
            default : begin
            end
         endcase
      end // MEM_LD_OPS_LB, MEM_LD_OPS_LBU
      MEM_LD_OPS_LH,
      MEM LD OPS LHU: begin
         case (mem2dmem.addr[1])
            1'b0 : begin
               dmem_rdata_hword = dmem2mem.data_rd[15:0];
            end
                      . . .
         endcase
      end // MEM_LD_OPS_LH, MEM_LD_OPS_LHU
      MEM_LD_OPS_LW : begin
         dmem_rdata_word = dmem2mem.data_rd;
      end
      default : begin
      end
   endcase // mem_ld_ops
end
```

Listing 5.3. Asynchronous data memory read for load operation.

Next we need to perform either sign- or zero-extension of the received data, before it is put into the destination register, as illustrated below.

Listing 5.4. Sign- or zero-extension of the loaded data.

Store Operation - Memory Access Phase (M)

Listing 7.1 illustrates setting up the signals for data memory access, which are equally applicable for store operation. In addition, the data that is to be stored and the corresponding mask are also prepared for the store operation, which resolve the data size as well as its address location. The code segment below illustrates this aspect of the data memory access.

```
// Prepare the write data and mask for store
always comb begin
   mem2dmem.data wr = '0;
   mem2dmem.mask
                   = '0;
   case (exe2mem_ctrl.mem_st_ops)
      MEM_ST_OPS_SB : begin
         case (mem2dmem.addr[1:0])
            2'b00 : begin
               mem2dmem.data wr[7:0] = exe2mem data.rs2 data[7:0];
               mem2dmem.mask = 4'b0001;
            end
            2'b11 : begin
               mem2dmem.data wr[31:24] = exe2mem data.rs2 data[31:24];
               mem2dmem.mask = 4'b1000;
            end
            default : begin
            end
         endcase
      end // MEM_ST_OPS_SB
      MEM ST OPS SH : begin
         case (mem2dmem.addr[1])
            1'b0 : begin
```

Listing 5.5. Data and mask preparation for store operation.

Finally the data prepared during the memory phase for store operation is sent to the data memory for store operation and is illustrated in the below code segment.

Listing 5.6. Storing the data synchronously to the data memory.

Load/Store Operation - Decode Phase

The decode operation for load and store instructions use **func3** bit-field of the instruction machine code to define the size and type of the data variable that is to be exchanged with the data memory. Recall that load instructions are I-type while store operations follow S-type encoding format. The memory address for load/store operations is constructed using register-offset memory addressing mode. The code listings implementing the load and store operations at instruction decode phase are given in Listing 7.7 and 7.8, respectively.

```
// Load operations
OPCODE_LOAD_INST : begin
   id2exe_ctrl.rd_wb_sel = RD_WB_MEM;
   id2exe_ctrl.alu_opr1_sel = ALU_OPR1_REG;
   id2exe_ctrl.alu_opr2_sel = ALU_OPR2_IMM;
   id2exe_ctrl.alu_ops = ALU_OPS_ADD;
   id2exe_ctrl.rd wr req
                         = 1'b1;
    case (funct3_opcode)
                                                               // Load byte signed
              3'b000 : id2exe_ctrl.mem_ld_ops = MEM_LD_OPS_LB;
              3'b001 : id2exe_ctrl.mem_ld_ops = MEM_LD_OPS_LH; // Load halfword signed
              3'b010 : id2exe_ctrl.mem_ld_ops = MEM_LD_OPS_LW; // Load word
              3'b100 : id2exe_ctrl.mem_ld_ops = MEM_LD_OPS_LBU; // Load byte unsigned
              3'b101 : id2exe ctrl.mem ld ops = MEM LD OPS LHU; // Load halfword unsigned
              default : id2exe_ctrl.mem_ld_ops = MEM_LD_OPS_NONE; // Load type unknown
   endcase // funct3_opcode
end // OPCODE LOAD INST
```

Listing 5.7. Instruction decoding for load operation.

```
// Store operations
OPCODE_STORE_INST : begin
   id2exe_ctrl.alu_opr1_sel = ALU_OPR1_REG;
   id2exe_ctrl.alu_opr2_sel = ALU_OPR2_IMM;
   id2exe_ctrl.alu_ops = ALU_OPS_ADD;
                          = {{21{instr_codeword[31]}}, instr_codeword[30:25],
   id2exe_data.imm
                                   instr_codeword[11:7]};
    case (funct3_opcode)
              3'b000 : id2exe_ctrl.mem_st_ops = MEM_ST_OPS_SB; // Store byte signed
              3'b001 : id2exe_ctrl.mem_st_ops = MEM_ST_OPS_SH;
                                                                 // Store halfword signed
              3'b010 : id2exe_ctrl.mem_st_ops = MEM_ST_OPS_SW;
                                                                 // Store word
              default : id2exe_ctrl.mem_st_ops = MEM_ST_OPS_NONE; // Store word
   endcase // funct3_opcode
end // OPCODE STORE INST
```

Listing 5.8. Instruction decoding for store operation.

Load/Store Operation - Execute Phase

The address generation for load/store operations during the instruction execution phase simply uses the ADD operation for register-immediate offset addressing.